



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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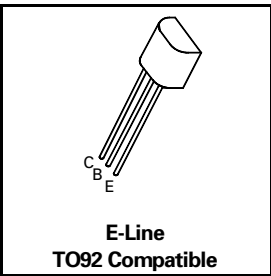
PNP SILICON PLANAR MEDIUM POWER TRANSISTORS

ZTX750
ZTX751

ISSUE 2 – JULY 94

FEATURES

- * 60 Volt V_{CE0}
- * 2 Amp continuous current
- * Low saturation voltage
- * $P_{tot} = 1$ Watt



ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	ZTX750	ZTX751	UNIT
Collector-Base Voltage	V_{CBO}	-60	-80	V
Collector-Emitter Voltage	V_{CEO}	-45	-60	V
Emitter-Base Voltage	V_{EBO}	-5		V
Peak Pulse Current	I_{CM}	-6		A
Continuous Collector Current	I_C	-2		A
Power Dissipation: at $T_{amb}=25^{\circ}C$ derate above $25^{\circ}C$	P_{tot}	1 5.7		W mW/ $^{\circ}C$
Operating and Storage Temperature Range	$T_j; T_{stg}$	-55 to +200		$^{\circ}C$

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}C$ unless otherwise stated).

PARAMETER	SYMBOL	ZTX750			ZTX751			UNIT	CONDITIONS.
		MIN.	TYP.	MAX.	MIN.	TYP.	MAX.		
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-60			-80			V	$I_C = -100\mu A$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-45			-60			V	$I_C = -10mA$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-5			-5			V	$I_E = -100\mu A$
Collector Cut-Off Current	I_{CBO}			-0.1 -10			-0.1 -10	μA μA μA μA	$V_{CB} = -45V$ $V_{CB} = -60V$ $V_{CB} = -45V, T_{amb} = 100^{\circ}C$ $V_{CB} = -60V, T_{amb} = 100^{\circ}C$
Emitter Cut-Off Current	I_{EBO}			-0.1			-0.1	μA	$V_{EB} = -4V$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$		-0.15 -0.28	-0.3 -0.5		-0.15 -0.28	-0.3 -0.5	V V	$I_C = -1A, I_B = -100mA$ $I_C = -2A, I_B = -200mA$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$		-0.9	-1.25		-0.9	-1.25	V	$I_C = -1A, I_B = -100mA$

ZTX750 ZTX751

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}\text{C}$ unless otherwise stated).

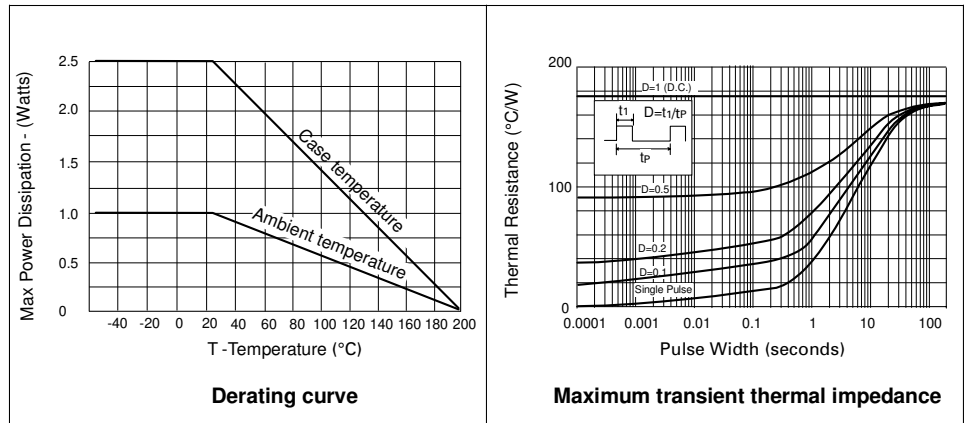
PARAMETER	SYMBOL	ZTX750			ZTX751			UNIT	CONDITIONS.
		MIN.	TYP.	MAX.	MIN.	TYP.	MAX.		
Transition Frequency	f_T	100	140		100	140		MHz	$I_C = -100\text{mA}$, $V_{CE} = -5\text{V}$ $f = 100\text{MHz}$
Switching Times	t_{on}		40			40		ns	$I_C = -500\text{mA}$, $V_{CC} = -10\text{V}$ $I_{B1} = I_{B2} = -50\text{mA}$
	t_{off}		450			450		ns	
Output Capacitance	C_{obo}			30			30	pF	$V_{CB} = 10\text{V}$ $f = 1\text{MHz}$

*Measured under pulsed conditions. Pulse width=300 μs . Duty cycle $\leq 2\%$

THERMAL CHARACTERISTICS

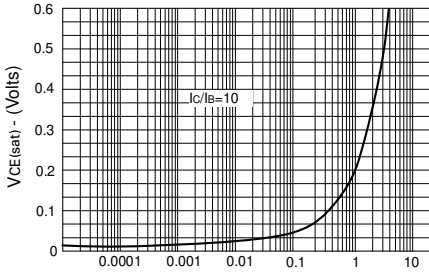
PARAMETER	SYMBOL	MAX.	UNIT
Thermal Resistance: Junction to Ambient ₁	$R_{th(j-amb)1}$	175	$^{\circ}\text{C/W}$
Junction to Ambient ₂	$R_{th(j-amb)2} \dagger$	116	$^{\circ}\text{C/W}$
Junction to Case	$R_{th(j-case)}$	70	$^{\circ}\text{C/W}$

\dagger Device mounted on P.C.B. with copper equal to 1 sq. Inch minimum.



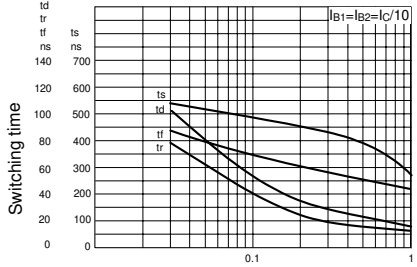
ZTX750 ZTX751

TYPICAL CHARACTERISTICS



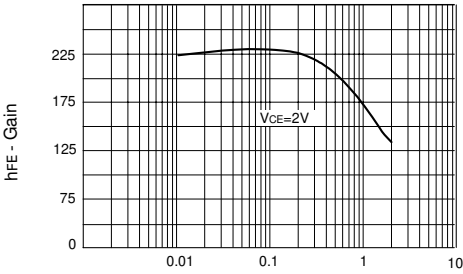
I_C - Collector Current (Amps)

$V_{CE(sat)}$ v I_C



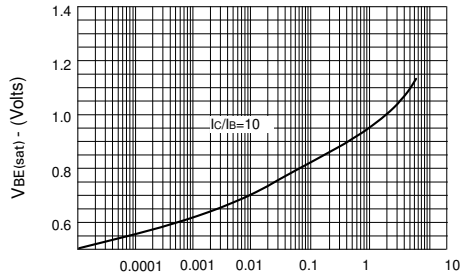
I_C - Collector Current (Amps)

Switching Speeds



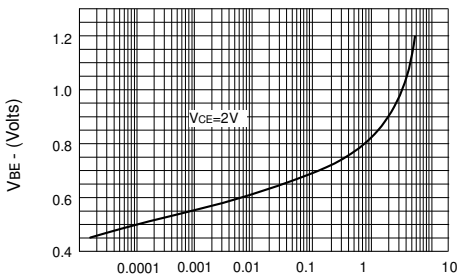
I_C - Collector Current (Amps)

h_{FE} v I_C



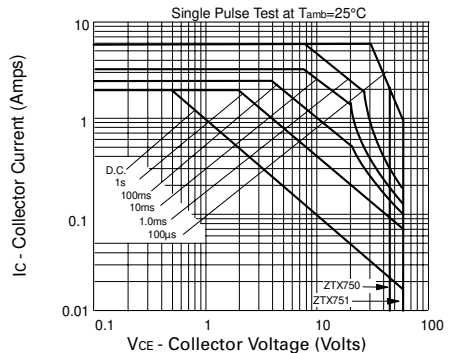
I_C - Collector Current (Amps)

$V_{BE(sat)}$ v I_C



I_C - Collector Current (Amps)

$V_{BE(on)}$ v I_C



V_{CE} - Collector Voltage (Volts)

Safe Operating Area